

**High Reliability, Radiation Hardened Octal Buffer/Line Driver, Three-State, Inverting**

Intersil's Satellite Applications Flow™ (SAF) devices are fully tested and guaranteed to 100kRAD total dose. These QML Class T devices are processed to a standard flow intended to meet the cost and shorter lead-time needs of large volume satellite manufacturers, while maintaining a high level of reliability.

The Intersil ACTS240T is a Radiation Hardened High Reliability, High-Speed CMOS/SOS Octal Buffer/Line Driver with three-state outputs having two active low enable inputs. Each enable input controls a set of four inverting buffer/line drivers. A HIGH on the enable input places the outputs in a high impedance state.

**Specifications**

Specifications for Rad Hard QML devices are controlled by the Defense Supply Center in Columbus (DSCC). The SMD numbers listed below must be used when ordering.

**Detailed Electrical Specifications for the ACTS240T are contained in SMD 5962-96717.** A "hot-link" is provided from our website for downloading.

[www.intersil.com/spacedefense/newsafclasst.asp](http://www.intersil.com/spacedefense/newsafclasst.asp)

Intersil's Quality Management Plan (QM Plan), listing all Class T screening operations, is also available on our website.

[www.intersil.com/quality/manuals.asp](http://www.intersil.com/quality/manuals.asp)

**Ordering Information**

ORDERING NUMBER	PART NUMBER	TEMP. RANGE (°C)
5962R9671701TRC	ACTS240DTR	-55 to 125
5962R9671701TXC	ACTS240KTR	-55 to 125

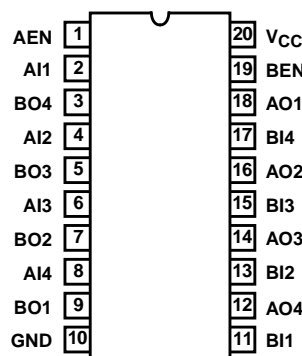
NOTE: **Minimum order quantity for -T is 150 units through distribution, or 450 units direct.**

**Features**

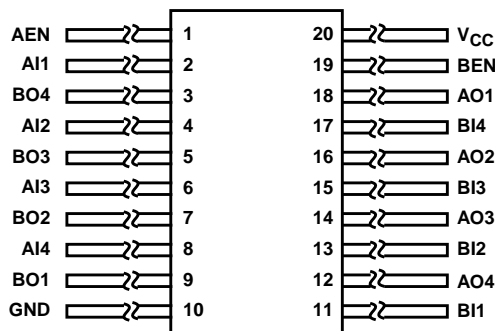
- QML Class T, Per MIL-PRF-38535
- Radiation Performance
  - Gamma Dose ( $\gamma$ )  $1 \times 10^5$  RAD(Si)
  - Latch-Up Free Under Any Conditions
  - Single Event Upset (SEU) Immunity:  $<1 \times 10^{-10}$  Errors/Bit/Day (Typ)
  - SEU LET Threshold . . . . .  $>100$  MEV-cm<sup>2</sup>/mg
- 1.25 Micron Radiation Hardened SOS CMOS
- Significant Power Reduction Compared to ALSTTL Logic
- DC Operating Voltage Range . . . . . 4.5V to 5.5V
- Input Logic Levels
  - $V_{IL} = 0.8V$  Max
  - $V_{IH} = V_{CC}/2$  Min
- Fast Propagation Delay . . . . . 17.5ns (Max), 12ns (Typ)

**Pinouts**

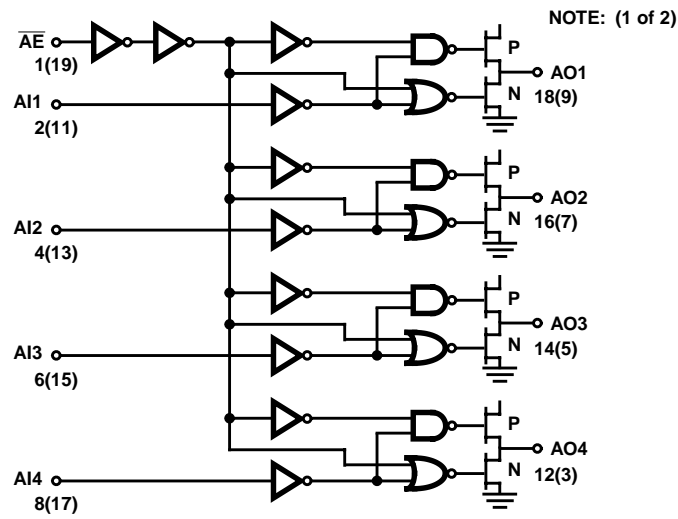
**ACTS240T (SBDIP), CDIP2-T20**  
TOP VIEW



**ACTS240T (FLATPACK), CDFP4-F20**  
TOP VIEW



Functional Diagram



TRUTH TABLE

INPUTS		OUTPUT
$\overline{AE}, \overline{BE}$	AIn, BIn	AOn, BOn
L	L	H
L	H	L
H	X	Z

NOTE: H = High Voltage Level, L = Low Voltage Level,  
X = Immaterial, Z = High Impedance

**Die Characteristics**

**DIE DIMENSIONS:**

(2540μm x 2540μm x 533μm ±51μm)  
 100 x 100 x 21mils ±2mil

**METALLIZATION:**

Type: Al Si Cu  
 Thickness: 10.0kÅ ±2kÅ

**SUBSTRATE POTENTIAL:**

Unbiased (Silicon on Sapphire)  
 Bond Pad #20 (V<sub>CC</sub>) First  
 Bond Pad #10 (Gnd) Uses Two Bond Wires  
 Bond Pad #20 (V<sub>CC</sub>) Uses Two Bond Wires

**BACKSIDE FINISH:**

Sapphire

**PASSIVATION:**

Type: Silox (SiO<sub>2</sub>)  
 Thickness: 8.0kÅ ±1.0kÅ

**WORST CASE CURRENT DENSITY:**

< 2.0e5 A/cm<sup>2</sup>

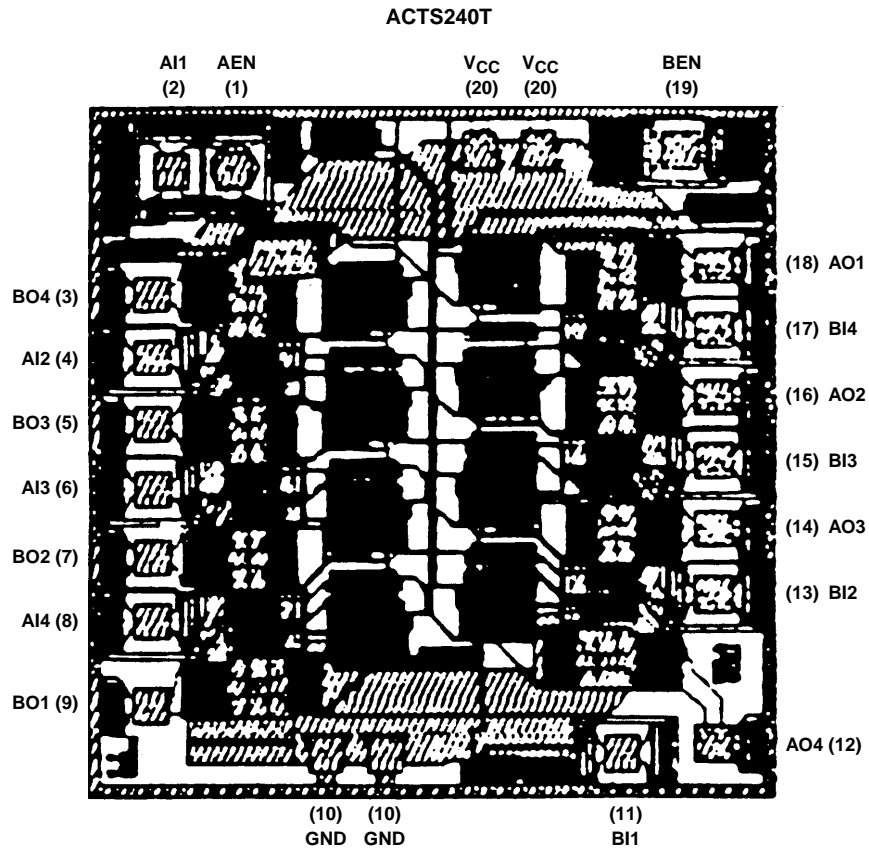
**TRANSISTOR COUNT:**

164

**PROCESS:**

CMOS SOS

**Metallization Mask Layout**



All Intersil semiconductor products are manufactured, assembled and tested under **ISO9000** quality systems certification.

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